Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

### Overall Length:

Between 0.120 inches and 0.300 inches

# Terminal Length:

Between 1.000 inches and 1.500 inches

### **Overall Diameter:**

Between 0.060 inches and 0.107 inches

### Function For Which Designed:

Voltage reference

#### **Mounting Method:**

Terminal

**Features Provided:** 

Quality assurance level tx and burn in

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

11.7 regulator voltage

### Voltage Tolerance In Percent:

-5.0/+5.0

### **Current Rating Per Characteristic:**

45.00 milliamperes repetitive peak forward current

# **Power Rating Per Characteristic:**

500.0 milliwatts small-signal input power, common-collector preset

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### Terminal Type And Quantity:

2 uninsulated wire lead

### **Specification Data:**

81349-mil-s-19500/157 government specification

#### Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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